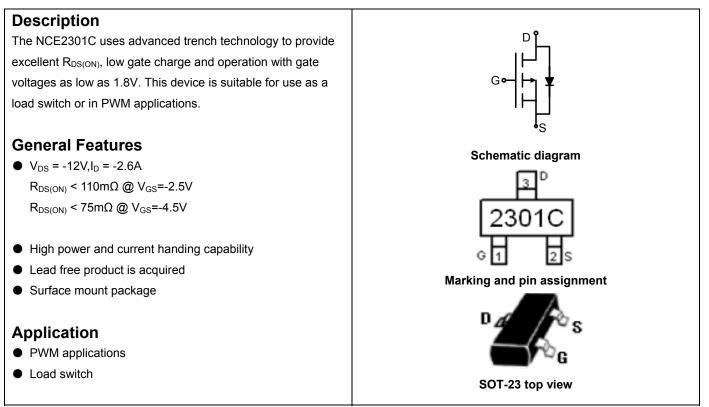


NCE P-Channel Enhancement Mode Power MOSFET



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
2301C	NCE2301C	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-12	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	I _D	-2.6	A
Drain Current -Pulsed (Note 1)	I _{DM}	-13	A
Maximum Power Dissipation	PD	0.9	W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	138	°C /W
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Electrical Characteristics (T_A=25[°]C unless otherwise noted)

Parameter	Symbol	Condition		Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250µA	-12		-	V
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-12V, V_{GS} =0V	-	-	-1	μA





NCE2301C

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I _{GSS}	V_{GS} =±12V, V_{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250\mu A$	-0.4	-0.7	-1	V
Drain-Source On-State Resistance	5	V _{GS} =-4.5V, I _D =-2 A	-	50	75	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-2.5V, I _D =-1.8A	-	72	110	mΩ
Forward Transconductance	g fs	V _{DS} =-5V,I _D =-1A	6	-	-	S
Dynamic Characteristics (Note4)						•
Input Capacitance	C _{lss}	V _{DS} =-6V,V _{GS} =0V,	-	325	-	PF
Output Capacitance	Coss		-	63	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	37	-	PF
Switching Characteristics (Note 4)						•
Turn-on Delay Time	t _{d(on)}	V _{DD} =-6V, R _L =5Ω	-	11	-	nS
Turn-on Rise Time	tr		-	5.5	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =-4.5V,R _{GEN} =3 Ω	-	22	-	nS
Turn-Off Fall Time	t _f		-	8	-	nS
Total Gate Charge	Qg		-	3.2	-	nC
Gate-Source Charge	Q _{gs}	V_{DS} =-6V,I _D =-2A,	-	0.6	-	nC
Gate-Drain Charge	Q _{gd}	V_{GS} =-4.5V	-	0.9	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =2A	-	-	-1.2	V
Diode Forward Current (Note 2)	I _S		-	-	-2.6	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board, $t \le 10$ sec.
- **3.** Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.
- 4. Guaranteed by design, not subject to production



NCE2301C



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Typical Electrical and Thermal Characteristics

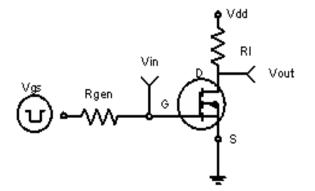
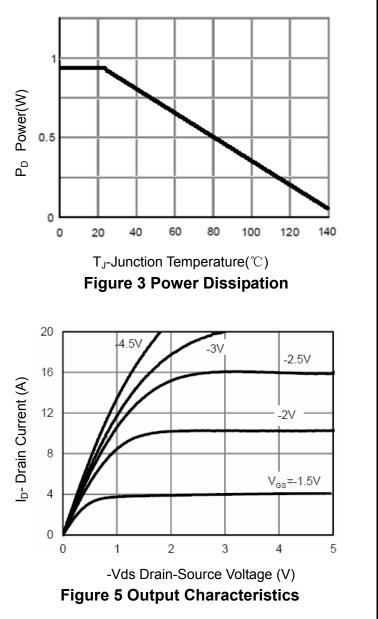


Figure 1:Switching Test Circuit



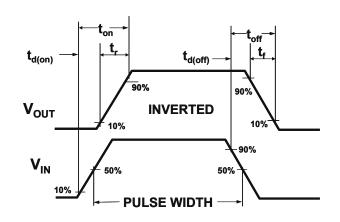
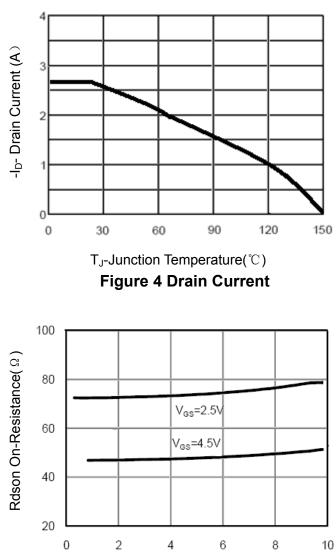


Figure 2:Switching Waveforms



-I_D- Drain Current (A) Figure 6 Drain-Source On-Resistance

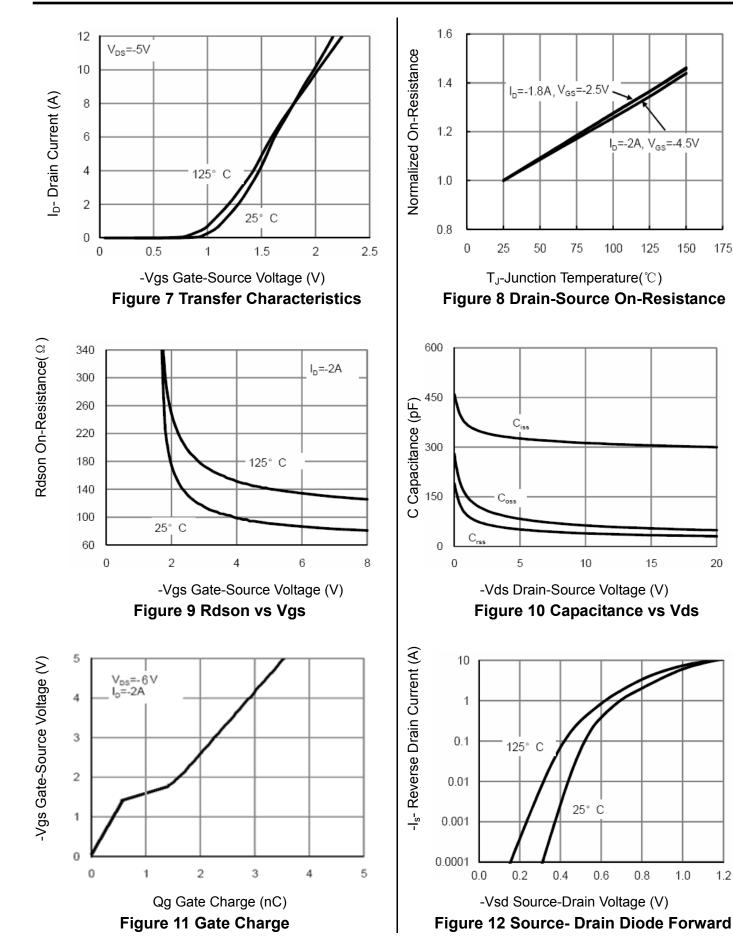




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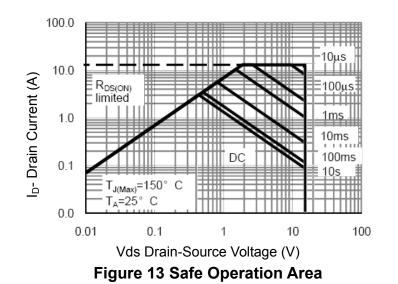
20



1.2







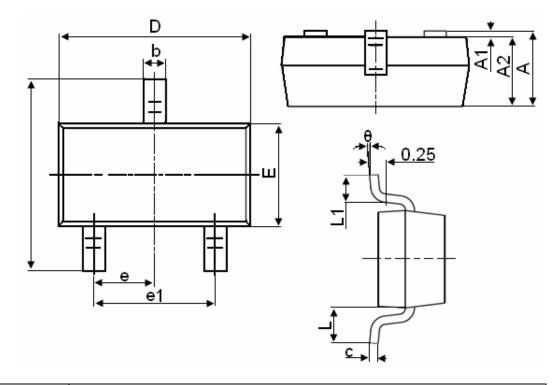
10 Transient Thermal Impedance D=T_{on}/T In descending order D=0.5, 0.3, 0.1, 0.05, 0.02, 0.01, single pulse T_{J,PK}=T_A+P_{DM}.Z_{0JA}.R_{0JA} r(t),Normalized Effective R_{өла}=138 ° C/W 11111 TH Ρ T, Single Pulse 0.00001 0.0001 0.001 0.01 0.1 10 100 1000 1 Square Wave Pluse Duration(sec)

Figure 14 Normalized Maximum Transient Thermal Impedance





SOT-23 Package Information



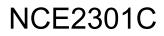
Symbol		Dimensions in Millimeters		
Symbol	MIN.	MAX.		
A	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
с	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L		0.550REF		
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact.







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